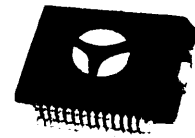
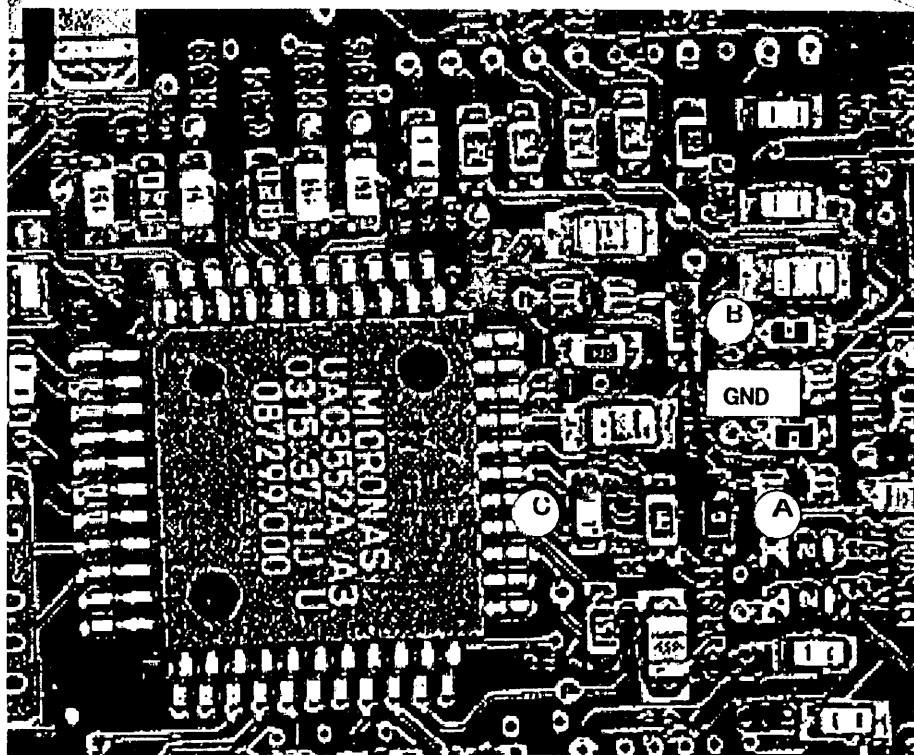
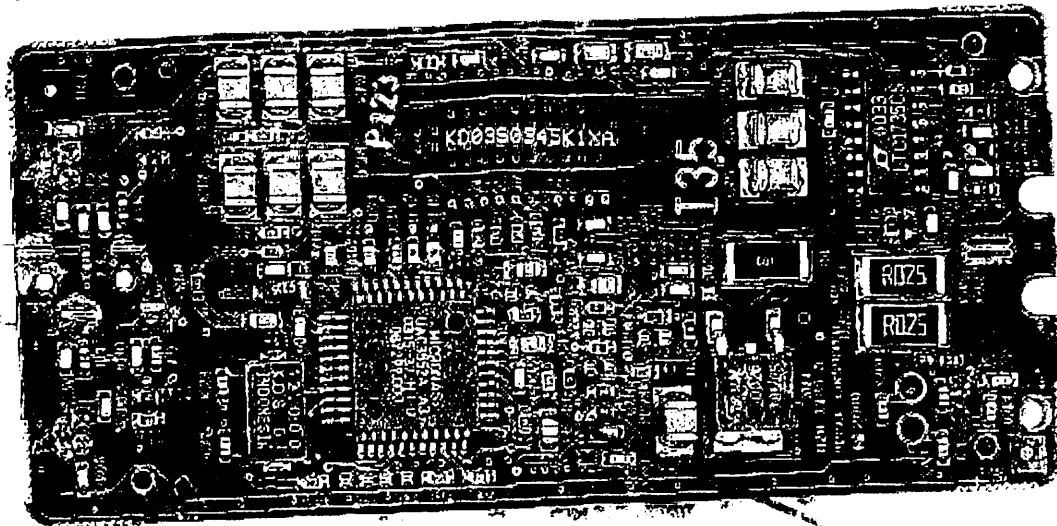


USBオーディオステレオアンプ基板
10Wステレオアンプ TA1101B 内蔵



参考資料



★注意★

- 1、ご使用になるには、半田付け作業を含む基板の改造が必要です。
- 2、無音時に、消費電流が500mA近く流れますので、パソコンUSB端子から電源を供給できません。5Vの外部電源(ACアダプタなど)が必要です。

■基板改造■

- 1、Aの0Ω抵抗を取り外す
- 2、取り外したAの0Ω抵抗の上側半田ランド、Bのチップ抵抗の上側電極、Cのチップコンデンサの上側電極の3点をビニール線などで、接続半田付けする。

★5V電源を接続し、WINDOWS—XPに接続すると、ヒューマンインターフェイス デバイスとして、USBオーディオと認識されます。

Absolute Maximum Ratings (Note 1)

SYMBOL	PARAMETER	Value	UNITS
V _{DD}	Supply Voltage	16	V
T _{STORE}	Storage Temperature Range	-40° to 150°	°C
T _A	Operating Free-air Temperature Range	0° to 70°	°C
P _{DISS}	Continuous Total Power Dissipation	Note 2	W

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur.

Note 2: See Power Dissipation Derating in the Applications Information section.

Operating Conditions (Note 3)

SYMBOL	PARAMETER	MIN.	TYP.	MAX.	UNITS
V _{DD}	Supply Voltage	8.5	12	13.2	V
V _{IH}	High-level Input Voltage (MUTE, SLEEP)	3.5			V
V _{IL}	Low-level Input Voltage (MUTE, SLEEP)			1	V

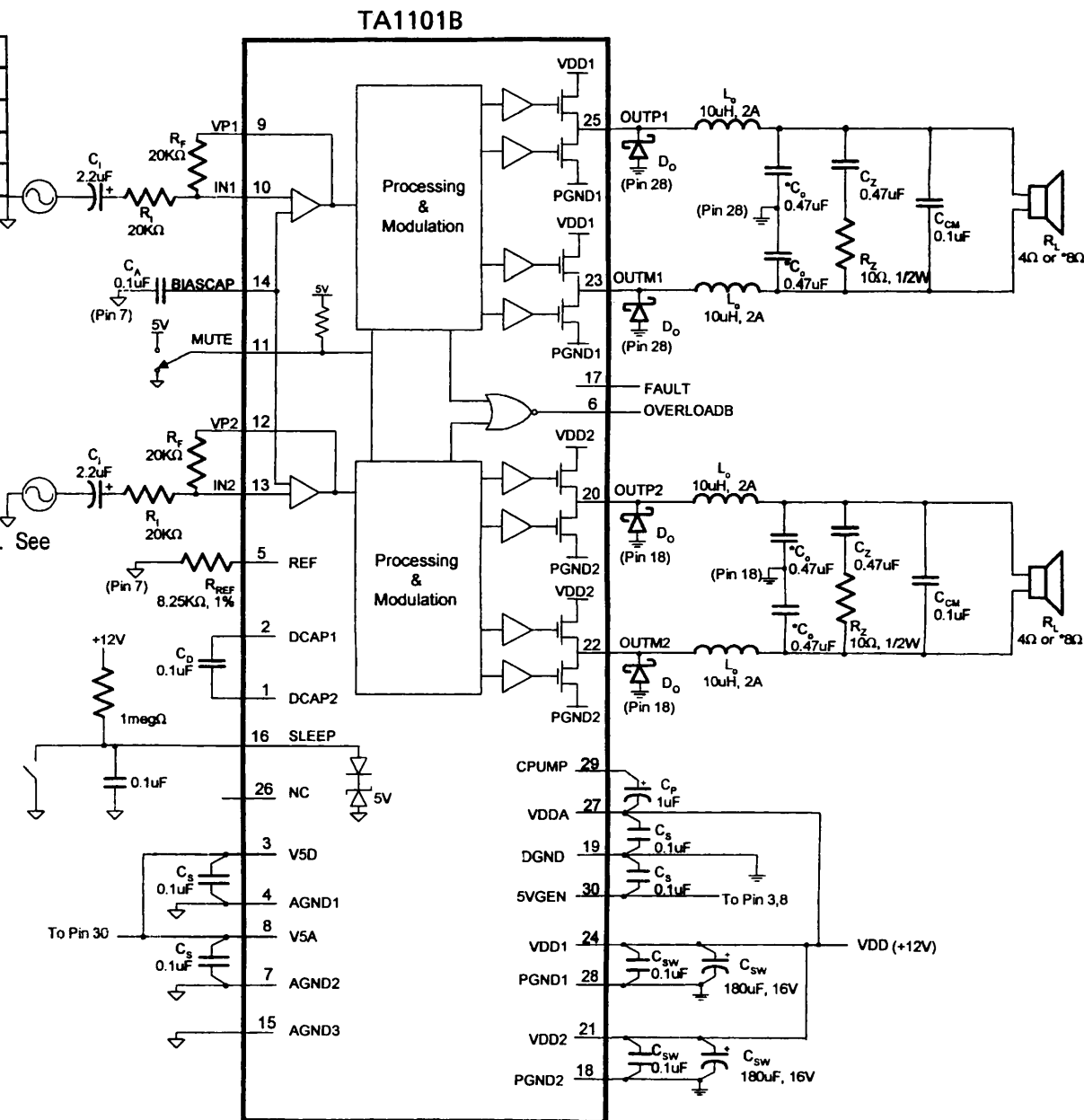
Note 3: Recommended Operating Conditions indicate conditions for which the device is functional. See Electrical Characteristics for guaranteed specific performance limits.

Electrical Characteristics

See Test/Application Circuit. Unless otherwise specified, $V_{DD} = 12V$, $f = 1kHz$, Measurement Bandwidth = 22kHz, $R_L = 4\Omega$, $T_A = 25^\circ C$. Package heat slug soldered to 2.8 square-inch PC pad.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNITS
P _O	Output Power (Continuous Average/Channel)	THD+N = 0.1% R _L = 4Ω R _L = 8Ω THD+N = 10% R _L = 4Ω R _L = 8Ω	9 5.5 12 8	11 6 16 10		W W W W
I _{DD,MUTE}	Mute Supply Current	MUTE = V _H		5.5	7	mA
I _{DD,SLEEP}	Sleep Supply Current	SLEEP = V _H		0.25	2	mA
I _q	Quiescent Current	V _{IN} = 0 V		61	75	mA
THD + N	Total Harmonic Distortion Plus Noise	P _O = 9W/Channel		0.04		%
IHF-IM	IHF Intermodulation Distortion	19kHz, 20kHz, 1:1 (IHF)		0.18	0.5	%
SNR	Signal-to-Noise Ratio	A-Weighted, P _{OUT} = 1W, R _L = 8Ω		89		dB
CS	Channel Separation	30kHz Bandwidth	50	55		dB
PSRR	Power Supply Rejection Ratio	Ripple = 100mV.	60	80		dB
η	Power Efficiency	P _{OUT} = 10W/Channel, R _L = 8Ω		88		%
V _{OFFSET}	Output Offset Voltage	No Load, MUTE = Logic Low		50	150	mV
V _{OH}	High-level output voltage (FAULT & OVERLOAD)		3.5			V
V _{OL}	Low-level output voltage (FAULT & OVERLOAD)				1	V
e _{OUT}	Output Noise Voltage	A-Weighted, input AC grounded		100		μV

Note: Minimum and maximum limits are guaranteed but may not be 100% tested.



參考資料

Note: Analog and Digital/Power Grounds must be connected locally at the TA1101B

 Analog Ground

 Digital/Power Ground

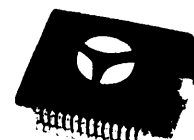
All Diodes Motorola MBRS130T3

- Use $C_o = 0.22\mu F$ for 8 Ohm loads

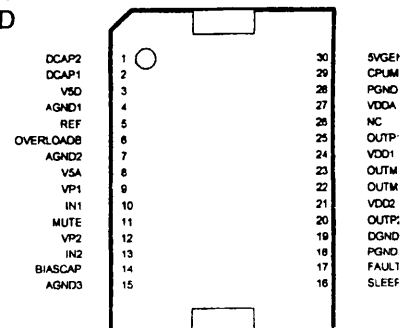
Stereo 10W (4Ω) Class-T™ Digital Audio Amplifier using Digital Power Processing™ Technology

September 2000

TA1101B



30-pin Power SOP Package (Top View)



General Description

The TA1101B is a 10W continuous average two-channel Class-T Digital Audio Power Amplifier IC using Tripath's proprietary Digital Power Processing™ technology. Class-T amplifiers offer both the audio fidelity of Class-AB and the power efficiency of Class-D amplifiers.

Applications

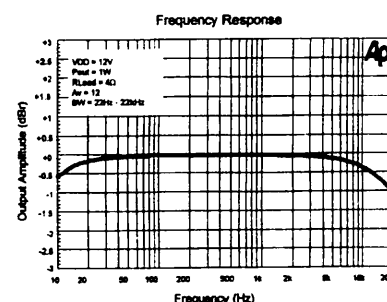
- Computer/PC Multimedia
- DVD Players
- Cable Set-Top Products
- Televisions
- Video CD Players
- Battery Powered Systems

Benefits

- Fully integrated solution with FETs
- Easier to design-in than Class-D
- Reduced system cost with no heat sink
- Dramatically improves efficiency versus Class-AB
- Signal fidelity equal to high quality linear amplifiers
- High dynamic range compatible with digital media such as CD, DVD, and Internet audio

Features

- Class-T architecture
- Single Supply Operation
- "Audiophile" Quality Sound
 - 0.04% THD+N @ 9W, 4Ω
 - 0.18% IHF-IM @ 1W, 4Ω
 - 6W @ 8Ω, 0.1% THD+N
 - 11W @ 4Ω, 0.1% THD+N
- High Power
 - 10W @ 8Ω, 10% THD+N
 - 15W @ 4Ω, 10% THD+N
- High Efficiency
 - 88% @ 10W, 8Ω
 - 81% @ 15W, 4Ω
- Dynamic Range = 102 dB
- Mute and Sleep inputs
- Turn-on & turn-off pop suppression
- Over-current protection
- Over-temperature protection
- Bridged outputs
- 30-pin Power SOP package



參考資料

Pin Description

Pin	Function	Description
1, 2	DCAP2, DCAP1	Charge pump switching pins. DCAP1 (pin 2) is a free running 300kHz square wave between VDDA and DGND (12Vpp nominal). DCAP2 (pin 1) is level shifted 10 volts above DCAP1 (pin 2) with the same amplitude (12Vpp nominal), frequency, and phase as DCAP1.
3, 8	V5D, V5A	Digital 5VDC, Analog 5VDC
4, 7, 15	AGND1, AGND2, AGND3	Analog Ground
5	REF	Internal reference voltage; approximately 1.0 VDC.
6	OVERLOADB	A logic low output indicates the input signal has overloaded the amplifier.
9, 12	VP1, VP2	Input stage output pins.
10, 13	IN1, IN2	Single-ended inputs. Inputs are a "virtual" ground of an inverting opamp with approximately 2.4VDC bias.
11	MUTE	When set to logic high, both amplifiers are muted and in idle mode. When low (grounded), both amplifiers are fully operational. If left floating, the device stays in the mute mode. Ground if not used.
14	BIASCAP	Input stage bias voltage (approximately 2.4VDC).
16	SLEEP	When set to logic high, device goes into low power mode. If not used, this pin should be grounded.
17	FAULT	A logic high output indicates thermal overload, or an output is shorted to ground, or another output.
18, 28	PGND2, PGND1	Power Grounds (high current)
19	DGND	Digital Ground
20, 22; 25, 23	OUTP2 & OUTM2; OUTP1 & OUTM1	Bridged outputs
21, 24	VDD2, VDD1	Supply pins for high current H-bridges, nominally 12VDC.
26	NC	Not connected
27	VDDA	Analog 12VDC
29	CPUMP	Charge pump output (nominally 10V above VDDA)
30	5VGEN	Regulated 5VDC source used to supply power to the input section (pins 3 and 8).

Typical Performance

